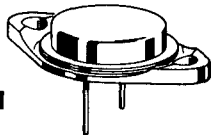


2N178 (GERMANIUM)
2N554
2N555

$V_{CB} = 15-30\text{ V}$
 $I_C = 3\text{ A}$
 $P_D = 10\text{ W}$



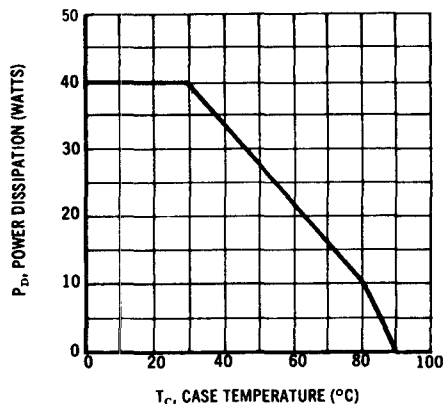
CASE 11
(TO-3)

PNP germanium power transistor for non-critical power amplifier and power switching applications requiring economical components.

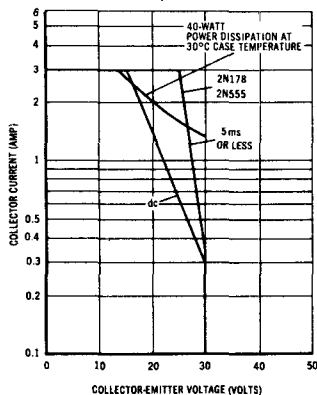
MAXIMUM RATINGS

Rating	Symbol	2N178	2N554	2N555	Unit
Collector-Emitter Voltage	V_{CER}	30	16	30	Vdc
Collector-Base Voltage	V_{CB}	30	15	30	Vdc
Emitter-Base Voltage	V_{EB}	20	15	15	Vdc
Collector Current	I_C	← 3.0 →			A dc
Total Device Dissipation @ $T_C = 80^\circ\text{C}$	P_D	← 10 →			Watts
Operating and Storage Junction Temperature Range	T_J, T_{stg}	← -40 to +90 →			$^\circ\text{C}$

POWER-TEMPERATURE DERATING CURVE
(All Types)

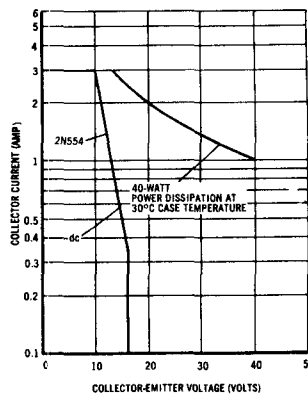


2N178, 2N555



SAFE OPERATING AREAS

2N554



The Safe Operating Area Curves indicate $I_C - V_{CE}$ limits below which the device will not go into secondary breakdown. Collector load lines for specific circuits must fall within the applicable Safe Area to avoid causing a collector-emitter short.

(Duty cycle of the excursions make no significant change in these safe areas.) To insure operation below the maximum T_J , the power-temperature derating curve must be observed for both steady state and pulse power conditions.

Power Transistors

2N178, 2N554, 2N555 (continued)

ELECTRICAL CHARACTERISTICS ($T_C = 25^\circ\text{C}$ unless otherwise noted)

Characteristic	Symbol	Min	Typ	Max	Unit
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OFF CHARACTERISTICS

Collector-Emitter Breakdown Voltage ($I_C = 330 \text{ mAdc}$, $R_{BE} = 10\Omega$)	2N178 2N554 2N555	BV_{CEr}	30 16 30	- - -	- - -	Vdc
Collector-Base Cutoff Current ($V_{CB} = 2.0 \text{ Vdc}$, $I_E = 0$)	2N178	I_{CBO}	-	0.05	-	mA
($V_{VB} = 30 \text{ Vdc}$, $I_E = 0$)	2N178		-	-	3.0	
($V_{CB} = 15 \text{ Vdc}$, $I_E = 0$)	2N554		-	-	10.0	
($V_{CB} = 30 \text{ Vdc}$, $I_E = 0$)	2N555		-	-	20.0	
($V_{CB} = 30 \text{ Vdc}$, $I_E = 0$, $T_C = 90^\circ\text{C}$)	2N178		-	-	20.0	
Emitter-Base Cutoff Current ($V_{BE} = 10 \text{ Vdc}$, $I_C = 0$)	2N178	I_{EBO}	-	-	2.0	mA

ON CHARACTERISTICS

DC Current Gain ($I_C = 0.5 \text{ Adc}$, $V_{CE} = 2.0 \text{ Vdc}$)	2N178 2N554 2N555	h_{FE}	15 - -	- 50 50	45 - -	-
Collector-Emitter Saturation Voltage ($I_C = 3.0 \text{ Adc}$, $I_B = 300 \text{ mAdc}$)		$V_{CE(sat)}$	-	0.6	-	Vdc

SMALL-SIGNAL CHARACTERISTICS

Common-Emitter Cutoff Frequency ($I_C = 0.5 \text{ Adc}$, $V_{CE} = 12 \text{ Vdc}$, $f = 1.0 \text{ kHz ref}$)	2N178 2N554 2N555	$f_{\alpha e}$	5.0 - -	- 6.0 6.0	- - -	kHz
Small-Signal Current Gain ($I_C = 0.5 \text{ Adc}$, $V_{CE} = 2.0 \text{ Vdc}$, $f = 1.0 \text{ kHz ref}$)	2N178 2N554 2N555	h_{fe}	- - -	30 55 55	- - -	-
Input Impedance ($I_C = 0.5 \text{ Adc}$, $V_{CE} = 2.0 \text{ Vdc}$, $f = 1.0 \text{ kHz}$)	2N178 2N554 2N555	h_{ie}	8.0 - -	25 25 25	- - -	Ohms

FUNCTIONAL TESTS

Power Gain ($V_{CE} = 12 \text{ Vdc}$, $I_C = 0.5 \text{ Adc}$, $P_{out} = 2.0$ Watts, $f = 1.0 \text{ kHz}$, $R_S = 10 \text{ Ohms}$, $R_L = 26.6 \text{ Ohms}$)	2N178 2N554 2N555	G_{PE}	28 20 25	- 35 35	33 - -	dB
Total Harmonic Distortion (Under same conditions as power gain)	2N178		-	-	5.0	%

